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捷多邦,专**您N54ABTH16245**加**SALE**4ABTH16245 **16-BIT BUS TRANSCEIVERS** WITH 3-STATE OUTPUTS SCBS662I - MARCH 1996 - REVISED MARCH 1999

SN74

- Members of the Texas Instruments Widebus[™] Family
- State-of-the-Art EPIC-IIB™ BiCMOS Design Significantly Reduces Power Dissipation
- Typical V_{OLP} (Output Ground Bounce) < 1 V at $V_{CC} = 5 V$, $T_A = 25^{\circ}C$
- **High-Impedance State During Power Up** and Power Down
- Distributed V_{CC} and GND Pin Configuration Minimizes High-Speed Switching Noise
- Flow-Through Architecture Optimizes PCB Layout
- High-Drive Outputs (–32-mA I_{OH}, 64-mA I_{OL})
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 500 mA Per **JESD 17**
- Package Options Include Plastic Shrink Small-Outline (DL), Thin Shrink Small-Outline (DGG), and Thin Very Small-Outline (DGV) Packages and 380-mil Fine-Pitch Ceramic Flat (WD) Package Using 25-mil Center-to-Center Spacings

description

The 'ABTH16245 devices are 16-bit noninverting 3-state transceivers that provide synchronous two-way communication between data buses. The control-function implementation minimizes external timing requirements.

These devices can be used as two 8-bit transceivers or one 16-bit transceiver. They allow data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (OE) input can be used to disable the devices so that the buses are effectively isolated.

When V_{CC} is between 0 and 2.1 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 2.1 V, OE should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

The SN54ABTH16245 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74ABTH16245 is characterized for operation from -40°C to 85°C.



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ABTH16245	. DC		D PACKAGE /, OR DL PACKAGE
1DIR [2	48] 10E
1B1 [47] 1A1
1B2 [46] 1A2
GND [45] GND

43

1A3

1A4

Vcc

1B3 5

1B4 🛛 6

V_{CC} L

1B5 8

2DIR

1B6 [9	40	1A6
gnd [10	39] GND
1B7 🛛	11	38] 1A7
1B8	12	37	1 A8
2B1	13		2A1
2B2	14	35	2A2
GND	15	34] GND
2B3 [16	33	2A3
2B4 🛛	17		2A4
V _{CC} [18] v _{cc}
2B5	19		2A5
2B6 🛛	20	29	2A6
gnd [28] GND
2B7 [22] 2A7
2B8	23	26	2A8
2DIR	24	25	20E

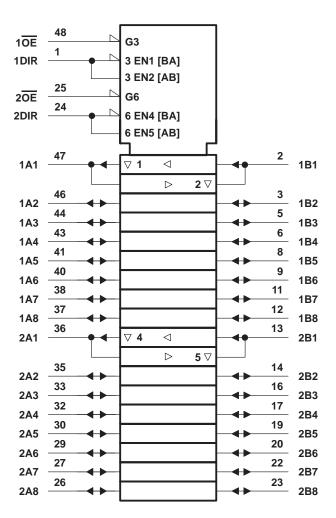
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FUNCTION TABLE

(each 8-bit section)

	· · · · · · · · · · · · · · · · · · ·							
IN	PUTS							
OE	DIR	OPERATION						
L	L	B data to A bus						
L	Н	A data to B bus						
н	Х	Isolation						

logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



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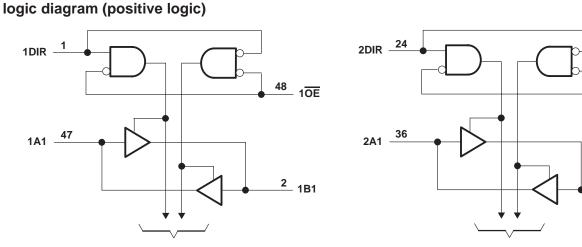
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25

13

– 2B1

2OE



To Seven Other Channels

To Seven Other Channels

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V_{CC}	to 7 V 5.5 V 96 mA 28 mA 18 mA 50 mA 9°C/W 3°C/W
94 DL package Storage temperature range, T _{stg}	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 3)

			SN54ABTH16245 SN74ABTH			H16245	UNIT
			MIN	MAX	MIN	MAX	UNIT
VCC	Supply voltage		4.5	5.5	4.5	5.5	V
VIH	High-level input voltage		2		2		V
VIL	Low-level input voltage			0.8		0.8	V
VI	Input voltage		0	VCC	0	VCC	V
ЮН	High-level output current			-24		-32	mA
IOL	Low-level output current	output current		48		64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	Outputs enabled		10		10	ns/V
TA	Operating free-air temperature	e		125	-40	85	°C

NOTE 3: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DAT	RAMETER	TEST CONDITIONS		Т	A = 25°C	>	SN54ABT	H16245	SN74ABTH	UNIT	
PA	RAMEIER		Inditions	MIN	TYP†	MAX	MIN	MAX	MIN	MAX	UNIT
VIK		V _{CC} = 4.5 V,	l _l = –18 mA			-1.2		-1.2		-1.2	V
		V _{CC} = 4.5 V,	I _{OH} = -3 mA	2.5			2.5		2.5		
Varia		V _{CC} = 5 V,	I _{OH} = -3 mA	3			3		3		v
Vон			I _{OH} = -24 mA	2			2				V
	V _{CC} = 4.5 V	I _{OH} = -32 mA	2*					2			
Vai		V _{CC} = 4.5 V	I _{OL} = 48 mA			0.55		0.55			V
VOL		$v_{CC} = 4.5 v$	I _{OL} = 64 mA			0.55*				0.55	v
V _{hys}					100						mV
IJ	Control inputs	V _{CC} = 5.5 V,	VI = V _{CC} or GND			±1		±1		±1	μA
•	A or B ports					±100		±100		±100	1
I			V _I = 0.8 V	100			100		100		μA
ll(hold)	V _{CC} = 4.5 V	V _I = 2 V	-100			-100		-100		μΑ	
		V _{CC} = 0 to 1.9 V				±50**		±50**			μA
IOZPL	J	$V_{CC} = 0 \text{ to } 2.1 \text{ V}$	OE = X			±50				±50	
		V _{CC} = 1.9 V to 0	$V_{O} = 0.5 \text{ V to } 2.7 \text{ V},$			±50**		±50**			μΑ
IOZPE)	$V_{CC} = 2.1 V \text{ to } 0$	OE = X			±50				±50	
loff		$V_{CC} = 0,$	VI or VO \leq 4.5 V			±100				±100	μΑ
ICEX		V _{CC} = 5.5 V, V _O = 5.5 V	Outputs high			50		50		50	μΑ
10‡		V _{CC} = 5.5 V,	V _O = 2.5 V	-50	-100	-180	-50	-180	-50	-180	mA
		V _{CC} = 5.5 V,	Outputs high			2		2		2	
ICC	A or B ports	$I_{0} = 0,$	Outputs low			32		32		32	mA
		$V_{I} = V_{CC}$ or GND	Outputs disabled			2		2		2	
2lCC§	3	$V_{CC} = 5.5 V$, One in Other inputs at V_{CC}				1.5		1.5		1.5	mA
Ci	Control inputs	V _I = 2.5 V or 0.5 V			3						pF
Cio	A or B ports	V _O = 2.5 V or 0.5 V			6						pF

* On products compliant to MIL-PRF-38535, this parameter does not apply.

** On products compliant to MIL-PRF-38535, this parameter is not production tested.

[†] All typical values are at V_{CC} = 5 V.

[‡]Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

§ This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.



switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER								
	FROM (INPUT)	TO (OUTPUT)	Vo T _A	C = 5 V λ = 25°C	l, ;	MIN	МАХ	UNIT
			MIN	TYP	MAX			
tPLH	A or B	B or A	1	2.2	3.6	0.5	4.1	ns
^t PHL		BUIA	1	2.3	3.8	0.5	4.4	115
^t PZH	ŌĒ	B or A	1	3.6	5.2	0.8	6.4	ns
^t PZL		BUIA	1	3.7	6.1	0.9	6.5	115
^t PHZ	OE	B or A	2	4.4	6.7	1.3	7.9	ns
^t PLZ	UE	BUIA	1.5	3.3	4.7	1.4	5.6	115

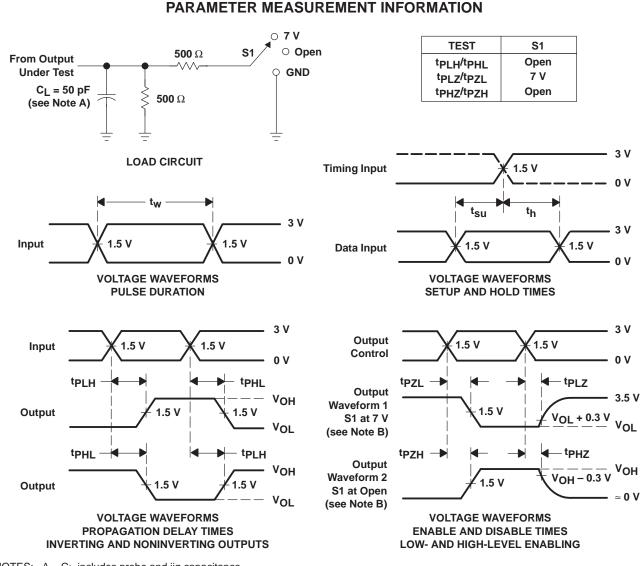
switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER								
	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 5 V, T _A = 25°C			MIN	МАХ	UNIT
			MIN	TYP	MAX			
tPLH	A or B	B or A	1	2.2	3.4	1	3.9	ns
^t PHL		DUX	1	2.3	3.7	1	4.2	115
^t PZH	ŌĒ	B or A	1	3.6	5.2	1	6.3	ns
^t PZL		BUIA	1	3.7	5.4	1	6.4	115
^t PHZ	OE	B or A	2	4.4	5.8	2	6.3	ns
^t PLZ	UE	BUIA	1.5	3.3	4.7	1.5	5.2	115



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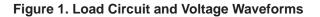
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NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_Q = 50 Ω , t_f \leq 2.5 ns, t_f \leq 2.5 ns.

D. The outputs are measured one at a time with one transition per measurement.





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